



74AHC1G00Q

SINGLE 2-INPUT POSITIVE NAND GATE

Description

The 74AHC1G00Q is an automotive compliant single, two-input positive NAND gate with a standard push-pull output. The device is designed for operation with a power supply range of 2.0V to 5.5V. The gate performs the positive Boolean function:

 $Y = \overline{A \cdot B}$ or $Y = \overline{A} + \overline{B}$

Features

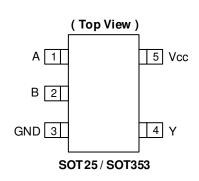
- Grade 1 Ambient Temperature Operation: -40°C to +125°C
- Supply Voltage Range from 2.0V to 5.5V
- ±8mA Output Drive at 4.5V
- CMOS Low-Power Consumption
- Schmitt Trigger Action at All Inputs Make the Circuit Tolerant for Slower Input Rise and Fall Time
- Inputs not Limited by Vcc
- Balanced Propagation Delays
- Balanced Drive Capability
- ESD Protection Tested per AEC-Q100
- Exceeds 2000-V Human Body Model (AEC-Q100-002)
- Exceeds 1000-V Charged Device Model (AEC-Q100-011)
- Latch-Up Exceeds 100mA (AEC-Q100-004)
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The 74AHC1G00Q is suitable for automotive applications requiring specific change control; this part is AEC-Q100 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/guality/product-definitions/

- Applications
- General Purpose Logic
- Wide Array of Products, such as:
 - Automotive Applications within Grade 1 Temperature Range
 - Industrial Computing/Controls/Automation
 - High Reliability Networking/Communications
 - Industrial/Agricultural Equipment

- Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 - 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 - 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Pin Assignments

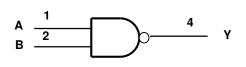




Pin Descriptions

| Pin Name | Description |
|----------|----------------|
| А | Data Input |
| В | Data Input |
| GND | Ground |
| Y | Data Output |
| Vcc | Supply Voltage |

Logic Diagram



Function Table

| Ing | Output | |
|-----|--------|---|
| Α | В | Y |
| н | Н | L |
| L | Х | Н |
| х | L | Н |

Absolute Maximum Ratings (Notes 4 & 5)

| Symbol | Description | Rating | Unit |
|---------|--|-------------------------------|------|
| ESD HBM | Human Body Model ESD Protection | 2 | kV |
| ESD CDM | Charged Device Model ESD Protection | 1 | kV |
| Vcc | Supply Voltage Range | -0.5 to 6.5 | V |
| VI | Input Voltage Range | -0.5 to 6.5 | V |
| Vo | Voltage Applied to Output in High or Low State | -0.5 to V _{CC} + 0.5 | V |
| Ік | Input Clamp Current VI < 0 | -20 | mA |
| Іок | Output Clamp Current (Vo < 0 or Vo > Vcc) | ±20 | mA |
| lo | Continuous Output Current (Vo = 0 to Vcc) | ±25 | mA |
| lcc | Continuous Current Through Vcc | 75 | mA |
| Ignd | Continuous Current Through GND | -75 | mA |
| TJ | Operating Junction Temperature | -40 to +150 | °C |
| Tstg | Storage Temperature | -65 to +150 | °C |
| PD | Total Power Dissipation (Note 6) | 250 | mW |

Notes: 4. Stresses beyond the absolute maximum can result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

5. Forcing the maximum allowed voltage could cause a condition exceeding the maximum current or conversely forcing the maximum current could cause a condition exceeding the maximum voltage. The ratings of both current and voltage must be maintained within the controlled range.

6. This will need to be derated at higher operating temperatures to prevent exceeding maximum T_J. Refer to package thermal characteristics section.



Recommended Operating Conditions (Note 7)

| Symbol | | Parameter | Min | Max | Unit | |
|--------|-------------------------------|--------------------------|------|------|------|--|
| Vcc | Operating Voltage | — | 2 | 5.5 | V | |
| | | V _{CC} = 2V | 1.5 | _ | | |
| VIH | High-Level Input Voltage | V _{CC} = 3V | 2.1 | _ | V | |
| | | V _{CC} = 5.5V | 3.85 | _ | | |
| | | V _{CC} = 2V | _ | 0.5 | | |
| VIL | Low-Level Input Voltage | V _{CC} = 3V | _ | 0.9 | V | |
| | | V _{CC} = 5.5V | _ | 1.65 | | |
| VI | Input Voltage | | 0 | 5.5 | V | |
| Vo | Output Voltage | | 0 | Vcc | V | |
| | | V _{CC} = 2V | _ | -50 | μA | |
| Іон | High-Level Output Current | $V_{CC} = 3.3V \pm 0.3V$ | _ | -4 | | |
| | | $V_{CC} = 5V \pm 0.5V$ | _ | -8 | mA | |
| | | V _{CC} = 2V | _ | 50 | μA | |
| IOL | Low-Level Output Current | $V_{CC} = 3.3V \pm 0.3V$ | _ | 4 | | |
| | | $V_{CC} = 5V \pm 0.5V$ | _ | 8 | mA | |
| | Input Transition Rise or Fall | $V_{CC} = 3.3V \pm 0.3V$ | _ | 100 | | |
| Δt/ΔV | Rate | $V_{CC} = 5V \pm 0.5V$ | _ | 20 | ns/V | |
| TA | Ambient Temperature | _ | -40 | +125 | °C | |

Note: 7. Unused inputs should be held at V_{CC} or Ground.

Electrical Characteristics (All typical values are at V_{CC} = 3.3V, T_A = +25°C)

| | . . | T 10 IVI | | | +25°C | | -40°C to | o +85°C | -40°C to | +125°C | |
|--------|------------------------------|--|-----------|------|-------|------|----------|---------|----------|--------|------|
| Symbol | Parameter | Test Conditions | Vcc | Min | Тур | Max | Min | Max | Min | Max | Unit |
| | | | | 1.9 | 2 | I | 1.9 | | 1.9 | _ | |
| | | ′і = Vін or Vі∟ он = -50µА | 3V | 2.9 | 3 | _ | 2.9 | _ | 2.9 | _ | |
| | High Loval | 10H = -50µA | 4.5V | 4.4 | 4.5 | _ | 4.4 | — | 4.4 | _ | |
| Vон | High Level Output Voltage | $V_I = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -4mA$ | 3V | 2.58 | _ | | 2.48 | _ | 2.40 | _ | V |
| | | Vı = Vıн or Vı∟ Іон = -8mA | 4.5V | 3.94 | _ | | 3.80 | | 3.70 | _ | |
| | | | 2V | _ | _ | 0.1 | _ | 0.1 | _ | 0.1 | |
| | | $V_{I} = V_{IH} \text{ or } V_{IL}$ | 3V | _ | | 0.1 | _ | 0.1 | | 0.1 | |
| | | I _{OL} = 50μΑ | 4.5V | | _ | 0.1 | _ | 0.1 | _ | 0.1 | |
| Vol | Low Level Output Voltage | VI = VIH or VIL IOL = 4mA | 3V | _ | _ | 0.36 | — | 0.44 | _ | 0.55 | V |
| | | V _I = V _{IH} or V _{IL} I _{OL} = 8mA | 4.5V | _ | _ | 0.36 | _ | 0.44 | _ | 0.55 | |
| lı | Input Current | VI = 5.5V or GND | 0 to 5.5V | _ | _ | ±0.1 | — | ±1 | — | ±2 | μA |
| lcc | Supply Current | VI = 5.5V or GND Io = 0 | 5.5V | _ | _ | 1 | _ | 10 | _ | 40 | μΑ |
| Cı | Input Capacitance | VI = VCC or GND | 5.5V | _ | 1.5 | 10 | _ | 10 | _ | 10 | pF |



Package Characteristics

| Symbol | Parameter | Package | Test Conditions | Min | Тур | Max | Unit |
|--------|---------------------|---------|-----------------|-----|-----|-----|---------------|
| 0 | Thermal Resistance | SOT25 | Note 0 | | 184 | _ | 0 0 MI |
| ΑLθ | Junction-to-Ambient | SOT353 | Note 8 | - | 385 | _ | °C/W |
| 0 | Thermal Resistance | SOT25 | Nista O | _ | 62 | _ | 00M |
| θις | Junction-to-Case | SOT353 | Note 8 | _ | 164 | _ | °C/W |

Note: 8. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

Switching Characteristics

Vcc = 3.3V ± 0.3V (See Figure 1)

| Parameter | From | То | Test | | +25°C | | -40°C te | o +85°C | -40°C to | +125°C | Unit |
|-----------|---------|----------|---------------|-----|-------|------|----------|---------|----------|--------|------|
| | (Input) | (Output) | Conditions | Min | Тур | Max | Min | Max | Min | Max | |
| | A | V | $C_L = 15 pF$ | 1.0 | 4.5 | 7.9 | 1.0 | 9.5 | 1.0 | 10.5 | ns |
| tpd | A or B | Y | CL = 50pF | 1.0 | 6.5 | 11.4 | 1.0 | 13.0 | 1.0 | 14.5 | ns |

Vcc = 5V ± 0.5V (See Figure 1)

| Parameter | From | То | Test | | +25°C | | -40°C te | o +85°C | -40°C to | +125°C | Unit |
|-----------|---------|----------|------------|-----|-------|-----|----------|---------|----------|--------|------|
| | (Input) | (Output) | Conditions | Min | Тур | Max | Min | Max | Min | Max | |
| | A | V | C∟ = 15pF | 1.0 | 3.5 | 5.5 | 1.0 | 6.5 | 1.0 | 7.0 | ns |
| tpd | A or B | Y | C∟ = 50pF | 1.0 | 4.9 | 7.5 | 1.0 | 8.5 | 1.0 | 9.5 | ns |

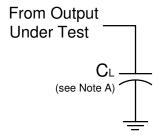
Operating Characteristics

 $T_A = +25^{\circ}C$

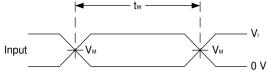
| | Parameter | Test Conditions | Vcc = 5V Typ | Unit |
|-----|-------------------------------|---------------------|-----------------|------|
| Cpd | Power Dissipation Capacitance | f = 1MHz No Load | 18 | pF |



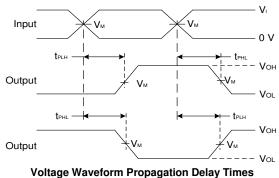
Measurement Information



| Vcc | Vcc Inputs | | Vм | CL | |
|-----------|------------|-------|-------|-------|--|
| VCC | Vi | tr/tr | ¥ W | UL UL | |
| 3.3V±0.3V | Vcc | ≤3ns | Vcc/2 | 15pF | |
| 5V±0.5V | Vcc | ≤3ns | Vcc/2 | 15pF | |
| 3.3V±0.3V | Vcc | ≤3ns | Vcc/2 | 50pF | |
| 5V±0.5V | Vcc | ≤3ns | Vcc/2 | 50pF | |



Voltage Waveform Pulse Duration



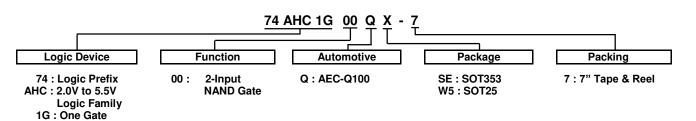
Inverting and Non-Inverting Outputs



- Notes:
- A. Includes test lead and test apparatus capacitance.
 B. All pulses are supplied at pulse repetition rate ≤ 1MHz.
 C. Inputs are measured separately one transition per measurement.



Ordering Information (Note 9)

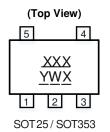


| Part Number | Package | Package | Package Size | 7" Таре | and Reel |
|----------------|---------|-----------------|--|------------------|--------------------|
| Fait Number | Code | (Notes 10 & 11) | Fackage Size | Quantity | Part Number Suffix |
| 74AHC1G00QSE-7 | SE | SOT353 | $\begin{array}{c} 2.15mm \times 2.1mm \times 1.1mm \\ 0.65mm \text{ lead pitch} \end{array}$ | 3000/Tape & Reel | -7 |
| 74AHC1G00QW5-7 | W5 | SOT25 | 3.0mm × 2.8 mm × 1.2 mm 0.95mm lead pitch | 3000/Tape & Reel | -7 |

Notes:

9. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.
 10. Pad layout as shown in Diodes Incorporated's package outline PDFs, which can be found on our website at http://www.diodes.com/package-outlines.html.
 11. The taping orientation is located on our website at https://www.diodes.com/assets/Packaging-Support-Docs/ap02007.pdf.

Marking Information



XXX : Identification Code Υ Year 0~9 : Week: A~Z 1~26 week W 1 a~z 27~52 week z represents week 52 and 53 X : A~ Z: Internal Code

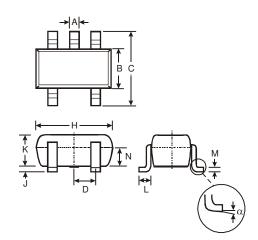
| Part Number | Package | Identification Code |
|----------------|---------|---------------------|
| 74AHC1G00QW5-7 | SOT25 | YRQ |
| 74AHC1G00QSE-7 | SOT353 | YRQ |



Package Outline Dimensions

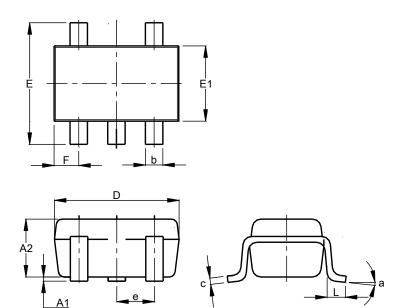
Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: SOT25



| SOT25 | | | | | |
|----------------------|-------|------|------|--|--|
| Dim | Min | Max | Тур | | |
| Α | 0.35 | 0.50 | 0.38 | | |
| В | 1.50 | 1.70 | 1.60 | | |
| С | 2.70 | 3.00 | 2.80 | | |
| D | - | - | 0.95 | | |
| н | 2.90 | 3.10 | 3.00 | | |
| J | 0.013 | 0.10 | 0.05 | | |
| К | 1.00 | 1.30 | 1.10 | | |
| L | 0.35 | 0.55 | 0.40 | | |
| М | 0.10 | 0.20 | 0.15 | | |
| Ν | 0.70 | 0.80 | 0.75 | | |
| α | 0° | 8° | - | | |
| All Dimensions in mm | | | | | |

(2) Package Type: SOT353



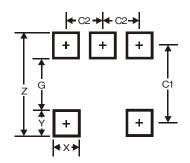
| | SOT353 | | | | |
|----------------------|-----------|------|-------|--|--|
| Dim | Min | Max | Тур | | |
| A1 | 0.00 | 0.10 | 0.05 | | |
| A2 | 0.90 | 1.00 | 0.95 | | |
| b | 0.10 | 0.30 | 0.25 | | |
| С | 0.10 | 0.22 | 0.11 | | |
| D | 1.80 | 2.20 | 2.15 | | |
| Е | 2.00 | 2.20 | 2.10 | | |
| E1 | 1.15 | 1.35 | 1.30 | | |
| е | 0.650 BSC | | | | |
| F | 0.40 | 0.45 | 0.425 | | |
| L | 0.25 | 0.40 | 0.30 | | |
| а | 0° | 8° | | | |
| All Dimensions in mm | | | | | |



Suggested Pad Layout

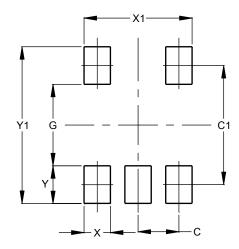
Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: SOT25



| Dimensions | Value |
|------------|-------|
| Z | 3.20 |
| G | 1.60 |
| Х | 0.55 |
| Y | 0.80 |
| C1 | 2.40 |
| C2 | 0.95 |

(2) Package Type: SOT353



| Dimensions | Value (in mm) |
|------------|------------------|
| С | 0.650 |
| C1 | 1.900 |
| G | 1.300 |
| Х | 0.420 |
| X1 | 1.720 |
| Ŷ | 0.600 |
| Y1 | 2.500 |

Mechanical Data

SOT25

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208
- Weight: 0.0158 grams (Approximate)

SOT353

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 3
- Weight: 0.0064 grams (Approximate)



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